

3STR1630

Low voltage high performance NPN power transistor

Features

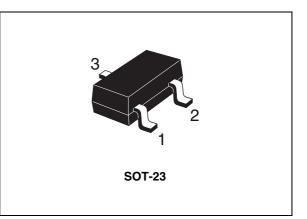
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package ECOPACK[®]2 grade for surface mounting circuits

Applications

- Strobe and LED drives
- Motor and relay drives
- DC-DC converters

Description

This device is an NPN transistor manufactured using low voltage planar technology with a double-metal process.





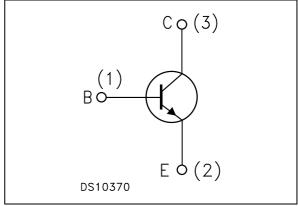


Table 1. Device summary

Order code	Marking	Package	Packing
3STR1630	1630	SOT-23	Tape and reel

1 Electrical ratings

Table 2.	Absolute	maximum	ratings
	/10001010	maximani	radingo

Symbol	Parameter	Value	Unit			
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	30	V			
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	30	V			
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5	V			
Ι _C	Collector current	6	Α			
I _{CM}	Collector peak current (t _P < 5 ms)	12	Α			
P _{TOT}	Total dissipation at T _{amb} = 25 °C	0.5	W			
T _{STG}	Storage temperature	-65 to 150	°C			
Τ _J	Max. operating junction temperature	150	°C			

Table 3.Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient max	250	°C/W

1. Device mounted on PCB area of 1 cm².



2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics							
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = 30 V				0.1	μA
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 4 V				0.1	μA
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = 100 μA		30			v
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage $(I_B = 0)$	I _C = 10 mA		30			v
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = 100 μA		5			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 1 A$ $I_{C} = 2 A$ $I_{C} = 5 A$	$I_B = 100 \text{ mA}$ $I_B = 40 \text{ mA}$ $I_B = 500 \text{ mA}$		60 140 240	90 190 300	mV mV mV
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{C} = 2 A$ $I_{C} = 5 A$	l _B = 40 mA l _B = 500 mA		830 1000	1100	mV mV
$h_{FE}^{(1)}$	DC current gain	$I_{C} = 50 \text{ mA}$ $I_{C} = 0.5 \text{ A}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$	$V_{CE} = 2 V$	210 180 170	260 90	560	
f _t	Transition frequency	I _C = 0.1 A	V _{CE} = 10 V		100		MHz
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 40 V,	f = 1 MHz		15		pF
t _{on} t _{off}	Resistive load Turn-on time Turn-off time	$I_{C} = 2.5 \text{ A}$ $I_{B1} = -I_{B2} = 1$ $V_{BE(off)} = -5$			90 450		ns ns

Table 4.	Electrical	characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq %

2.1 Electrical characteristics (curves)

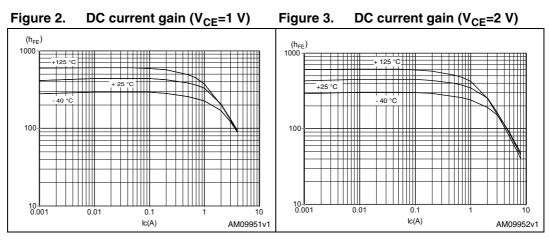


Figure 4. Collector-emitter saturation Figure 5. voltage (V_{CEsat} @ h_{FE}=10)

Collector-emitter saturation voltage (V_{CEsat} @ h_{FE}=50)

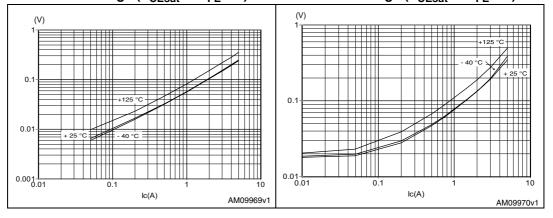
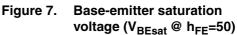
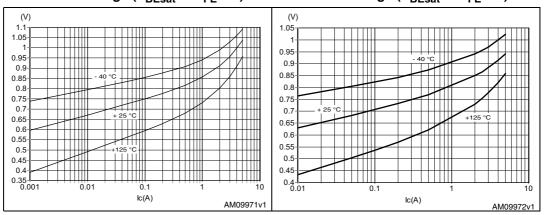


Figure 6. Base-emitter saturation voltage (V_{BEsat} @ h_{FE}=10)







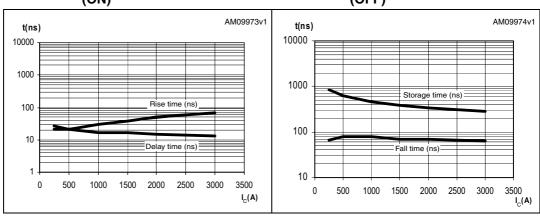
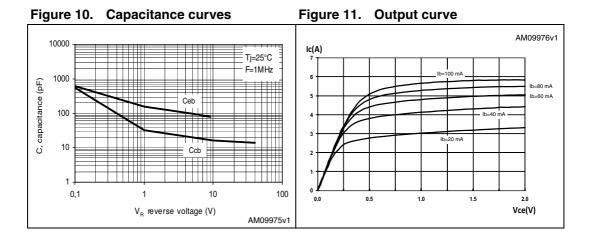


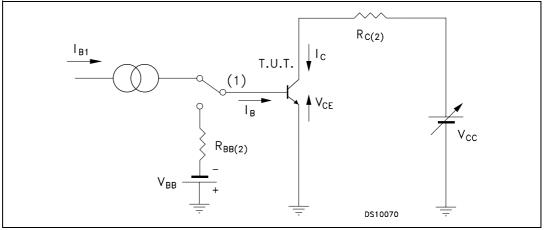
Figure 8. Resistive load switching time Figure 9. Resistive load switching time (ON) (OFF)





2.2 Test circuits





1. Fast electronic switch

2. Non-inductive resistor



3 Package mechanical data

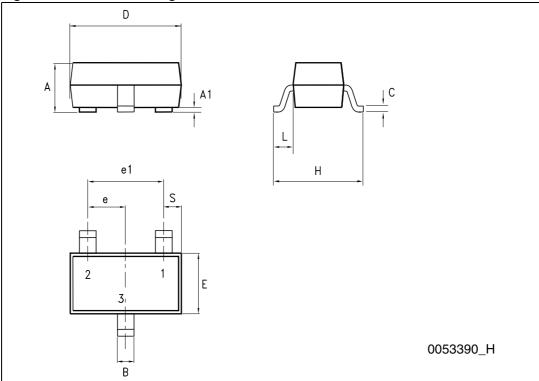
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Dim.		mm.		
Dini.	Min.	Тур.	Max.	
A	0.89		1.4	
A1	0		0.1	
В	0.3		0.51	
С	0.085		0.18	
D	2.75		3.04	
e	0.85		1.05	
e1	1.7		2.1	
E	1.2		1.6	
Н	2.1		2.75	
L		0.6		
S	0.35		0.65	

 Table 5.
 SOT-23 mechanical data







4 Revision history

Table 6.Document revision history

Date	Revision	Changes
02-Nov-2009	1	Initial release
17-Jan-2011 2 Removed "Preliminary data" text from		Removed "Preliminary data" text from coverpage header.
15-Jun-2011	3	Curves inserted Modified: <i>Table 4</i>



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